



TPS37xx-Q1

Dual-Channel, Low-Power, High-Accuracy Voltage Detectors

1 Features

- Qualified for Automotive Applications
- AEC-Q100 Qualified With the Following Results:
 - Device Temperature Grade 1: -40°C to 125°C
 - Ambient Operating Temperature Range
 - Device HBM ESD Classification Level H2
 - Device CDM ESD Classification Level C4B
- Two-Channel Detectors in Small Packages
- High-Accuracy Threshold and Hysteresis: 1.0%
- Low Quiescent Current: 2 μA (typ)
- Adjustable Detection Voltage Down to 1.2 V
- 5% and 10% Hysteresis Options
- Temperature Range: -40°C to $+125^{\circ}\text{C}$
- Push-Pull (TPS3779-Q1) and Open-Drain (TPS3780-Q1) Output Options
- Available in an SOT-23 Package

2 Applications

- DSPs, Microcontrollers, and Microprocessors
- Advanced Driver Assistance Systems (ADAS)
- Infotainment and Clusters
- Power-Supply Sequencing Applications

3 Description

The TPS3779-Q1 and TPS3780-Q1 are a family of high-accuracy, two-channel voltage detectors featuring low power and small solution size. The SENSE1 and SENSE2 inputs include hysteresis to reject brief glitches, thus ensuring stable output operation without false triggering. This device family offers different factory-set hysteresis options of 5% or 10%.

The TPS3779-Q1 and TPS3780-Q1 have adjustable SENSEx inputs that can be configured by an external resistor divider. When the voltage at the SENSE1 or SENSE2 input goes below the falling threshold, OUT1 or OUT2 is driven low, respectively. When SENSE1 or SENSE2 rises above the rising threshold, OUT1 or OUT2 goes high, respectively.

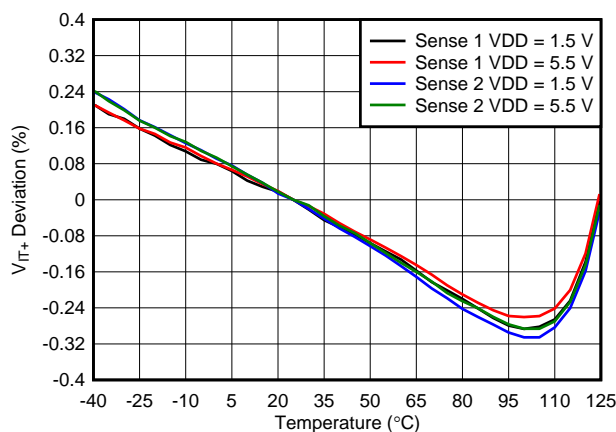
The devices have a very low quiescent current of 2 μA (typical) and provide a precise, space-conscious solution for voltage detection suitable for low-power, system-monitoring, and portable applications. The TPS3779-Q1 and TPS3780-Q1 operate from 1.5 V to 5.5 V, over the -40°C to $+125^{\circ}\text{C}$ temperature range.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS37xx-Q1	SOT-23 (6)	2.90 mm × 1.60 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

Sense Threshold (V_{IT+}) Deviation versus Temperature



Typical Schematic

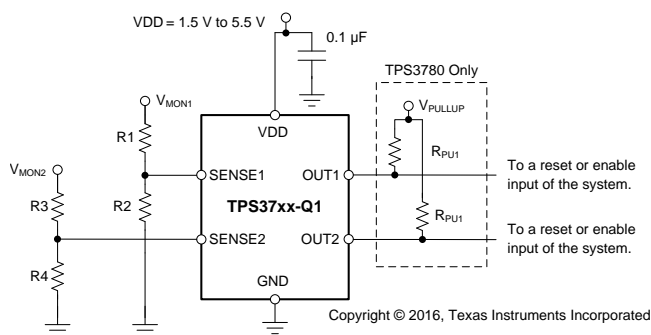


Table of Contents

1 Features	1	8.4 Device Functional Modes	11
2 Applications	1	9 Application and Implementation	12
3 Description	1	9.1 Application Information	12
4 Revision History	2	9.2 Typical Applications	13
5 Device Comparison Table	3	10 Power-Supply Recommendations	15
6 Pin Configuration and Functions	3	11 Layout	15
7 Specifications	4	11.1 Layout Guidelines	15
7.1 Absolute Maximum Ratings	4	11.2 Layout Example	15
7.2 ESD Ratings	4	12 Device and Documentation Support	16
7.3 Recommended Operating Conditions	4	12.1 Device Support	16
7.4 Thermal Information	4	12.2 Documentation Support	16
7.5 Electrical Characteristics	5	12.3 Receiving Notification of Documentation Updates	16
7.6 Timing Requirements	6	12.4 Related Links	16
7.7 Typical Characteristics	7	12.5 Community Resources	17
8 Detailed Description	10	12.6 Trademarks	17
8.1 Overview	10	12.7 Electrostatic Discharge Caution	17
8.2 Functional Block Diagrams	10	12.8 Glossary	17
8.3 Feature Description	11	13 Mechanical, Packaging, and Orderable Information	17

4 Revision History

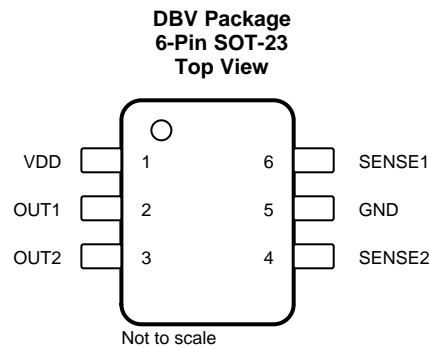
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (June 2016) to Revision A	Page
• Added TPS3780A-Q1 row to <i>Device Comparison Table</i>	3
• Added TPS37xxA-Q1 row to V_{IT-} parameter in <i>Electrical Characteristics</i> table	5

5 Device Comparison Table

PRODUCT	HYSTERESIS (%)	OUTPUT
TPS3779B-Q1	5	Push-pull
TPS3779C-Q1	10	Push-pull
TPS3780A-Q1	0.5	Open-drain
TPS3780B-Q1	5	Open-drain
TPS3780C-Q1	10	Open-drain

6 Pin Configuration and Functions



Pin Functions

NAME	NO.	I/O	DESCRIPTION
GND	5	—	Ground
OUT1	2	O	OUT1 is the output for SENSE1. OUT1 is asserted (driven low) when the voltage at SENSE1 falls below V_{IT-} . OUT1 is deasserted (goes high) after SENSE1 rises higher than V_{IT+} . OUT1 is a push-pull output for the TPS3779-Q1 and an open-drain output for the TPS3780-Q1. The open-drain device (TPS3780-Q1) can be pulled up to 5.5 V independent of VDD; a pullup resistor is required for this device.
OUT2	3	O	OUT2 is the output for SENSE2. OUT2 is asserted (driven low) when the voltage at SENSE2 falls below V_{IT-} . OUT2 is deasserted (goes high) after SENSE2 rises higher than V_{IT+} . OUT2 is a push-pull output for the TPS3779-Q1 and an open-drain output for the TPS3780-Q1. The open-drain device (TPS3780-Q1) can be pulled up to 5.5 V independent of VDD; a pullup resistor is required for this device.
SENSE1	6	I	This pin is connected to the voltage to be monitored with the use of an external resistor divider. When the voltage at this pin drops below the threshold voltage (V_{IT-}), OUT1 is asserted.
SENSE2	4	I	This pin is connected to the voltage to be monitored with the use of an external resistor divider. When the voltage at this pin drops below the threshold voltage (V_{IT-}), OUT2 is asserted.
VDD	1	I	Supply voltage input. Connect a 1.5-V to 5.5-V supply to VDD in order to power the device. Good analog design practice is to place a 0.1- μ F ceramic capacitor close to this pin (required for VDD < 1.5 V).

7 Specifications

7.1 Absolute Maximum Ratings

over operating junction temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage	VDD	−0.3	7	V
	OUT1, OUT2 (TPS3779-Q1 only)	−0.3	VDD + 0.3	
	OUT1, OUT2 (TPS3780-Q1 only)	−0.3	7	
	SENSE1, SENSE2	−0.3	7	
Current	OUT1, OUT2		±20	mA
Temperature	Operating junction, T _J ⁽²⁾	−40	125	°C
	Storage, T _{stg}	−65	150	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) For low-power devices, the junction temperature rise above the ambient temperature is negligible; therefore, the junction temperature is considered equal to the ambient temperature (T_J = T_A).

7.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000
		Charged-device model (CDM), per AEC Q100-011	±500

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

7.3 Recommended Operating Conditions

over operating junction temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
	Power-supply voltage	1.5		5.5	V
	Sense voltage	0		5.5	V
	Output voltage (TPS3779-Q1 only)	0		VDD + 0.3	V
	Output voltage (TPS3780-Q1 only)	0		5.5	V
R _{PU}	Pullup resistor (TPS3780-Q1 only)	1.5		10,000	kΩ
	Current	−5		5	mA
C _{IN}	Input capacitor		0.1		μF
T _J	Junction temperature	−40	25	125	°C

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS3779-Q1, TPS3780-Q1	UNIT
		DBV (SOT-23)	
		6 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	193.9	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	134.5	°C/W
R _{θJB}	Junction-to-board thermal resistance	39.0	°C/W
ψ _{JT}	Junction-to-top characterization parameter	30.4	°C/W
ψ _{JB}	Junction-to-board characterization parameter	38.5	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.5 Electrical Characteristics

all specifications are over the operating temperature range of $-40^{\circ}\text{C} < T_J < +125^{\circ}\text{C}$ and $1.5\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ (unless otherwise noted); typical values are at $T_J = 25^{\circ}\text{C}$ and $V_{DD} = 3.3\text{ V}$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VDD	Input supply range		1.5		5.5	V
V(POR)	Power-on-reset voltage ⁽¹⁾	$V_{OL}(\text{max}) = 0.2\text{ V}$, $I_{OL} = 15\text{ }\mu\text{A}$			0.8	V
IDD	Supply current (into VDD pin)	VDD = 3.3 V, no load		2.09	5.80	μA
		VDD = 5.5 V, no load		2.29	6.50	
VIT+	Positive-going input threshold voltage	$V_{(\text{SENSE}_x)}$ rising		1.194		V
			–1%		1%	
VIT–	Negative-going input threshold voltage	$V_{(\text{SENSE}_x)}$ falling		1.188		V
				1.134		
				1.074		
		$V_{(\text{SENSE}_x)}$ falling	–1%		1%	
ISENSEx	Input current	$V_{(\text{SENSE}_x)} = 0\text{ V}$ or VDD	–15		15	nA
VOL	Low-level output voltage	$V_{DD} \geq 1.5\text{ V}$, $I_{\text{SINK}} = 0.4\text{ mA}$			0.25	V
		$V_{DD} \geq 2.7\text{ V}$, $I_{\text{SINK}} = 2\text{ mA}$			0.25	
		$V_{DD} \geq 4.5\text{ V}$, $I_{\text{SINK}} = 3.2\text{ mA}$			0.30	
VOH	High-level output voltage (TPS3779-Q1 only)	$V_{DD} \geq 1.5\text{ V}$, $I_{\text{SOURCE}} = 0.4\text{ mA}$	0.8 VDD			V
		$V_{DD} \geq 2.7\text{ V}$, $I_{\text{SOURCE}} = 1\text{ mA}$	0.8 VDD			
		$V_{DD} \geq 4.5\text{ V}$, $I_{\text{SOURCE}} = 2.5\text{ mA}$	0.8 VDD			
IIK(OD)	Open-drain output leakage current (TPS3780-Q1 only)	High impedance, $V_{(\text{SENSE}_x)} = V_{(\text{OUT}_x)} = 5.5\text{ V}$	–250		250	nA

(1) Outputs are undetermined below $V_{(\text{POR})}$.

7.6 Timing Requirements

typical values are at $T_J = 25^\circ\text{C}$ and $V_{DD} = 3.3\text{ V}$; SENSEx transitions between 0 V and 1.3 V

	MIN	NOM	MAX	UNIT
$t_{PD(r)}$ SENSEx (rising) to OUTx propagation delay		5.5		μs
$t_{PD(f)}$ SENSEx (falling) to OUTx propagation delay		10		μs
t_{SD} Startup delay ⁽¹⁾		570		μs

- (1) During power-on or when a V_{DD} transient is below $V_{DD}(\text{min})$, the outputs reflect the input conditions 570 μs after V_{DD} transitions through $V_{DD}(\text{min})$.

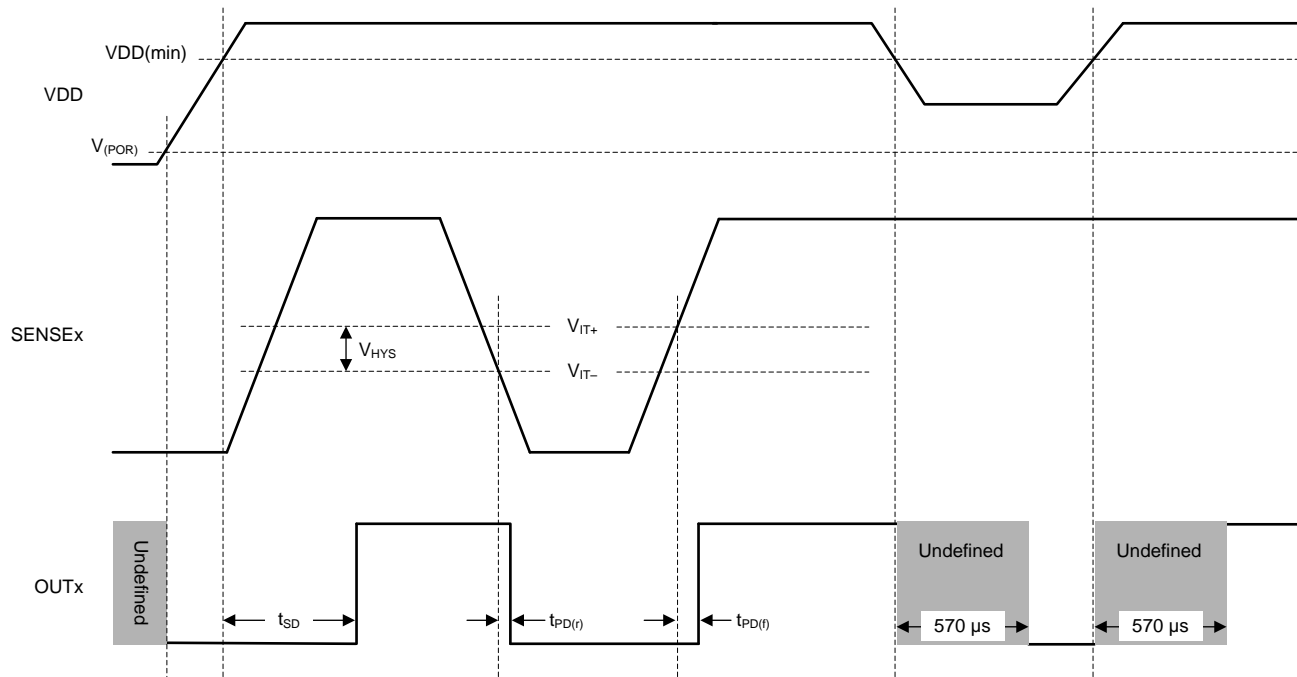


Figure 1. Timing Diagram

7.7 Typical Characteristics

at $T_J = 25^\circ\text{C}$ with a 0.1- μF capacitor close to VDD (unless otherwise noted)

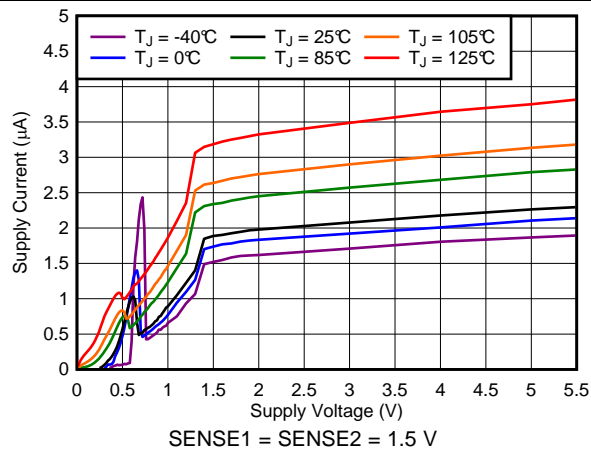


Figure 2. Supply Current vs Supply Voltage

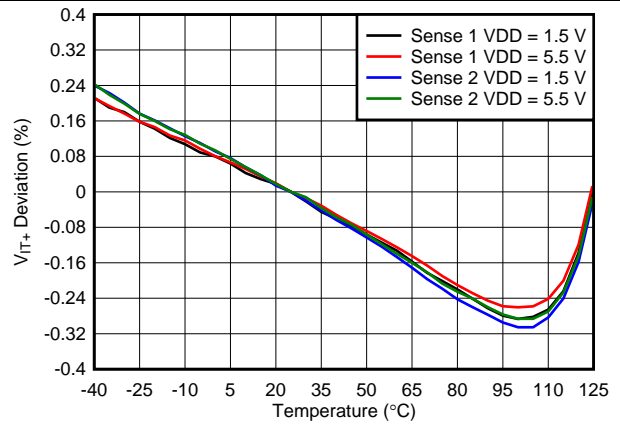


Figure 3. Sense Threshold (V_{IT+}) Deviation vs Temperature

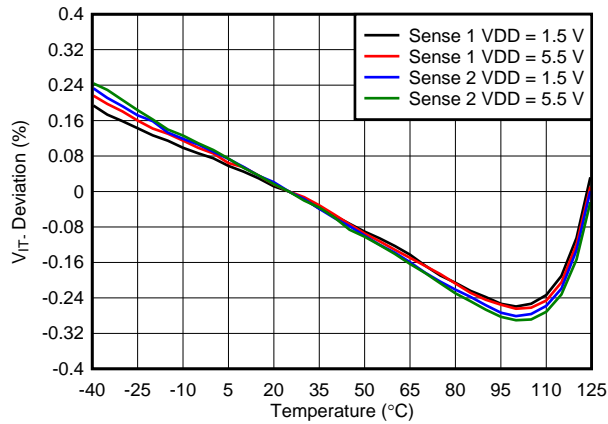


Figure 4. Sense Threshold (V_{IT-}) Deviation vs Temperature

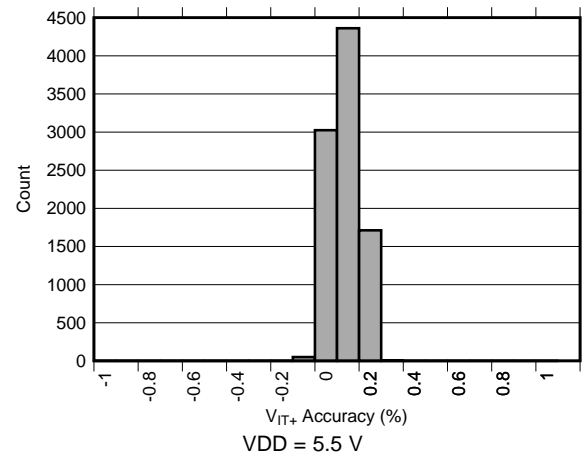


Figure 5. Sense Threshold (V_{IT+})

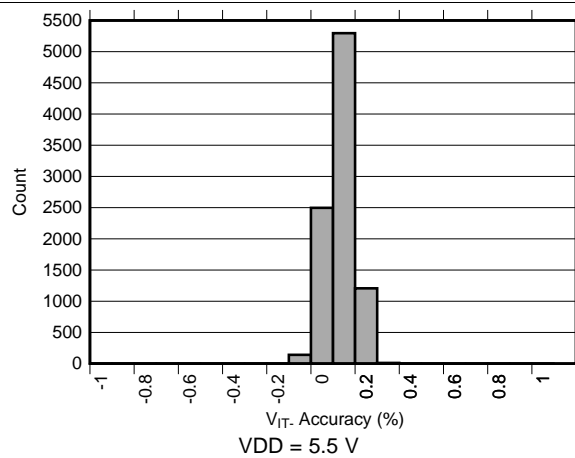


Figure 6. Sense Threshold (V_{IT-})

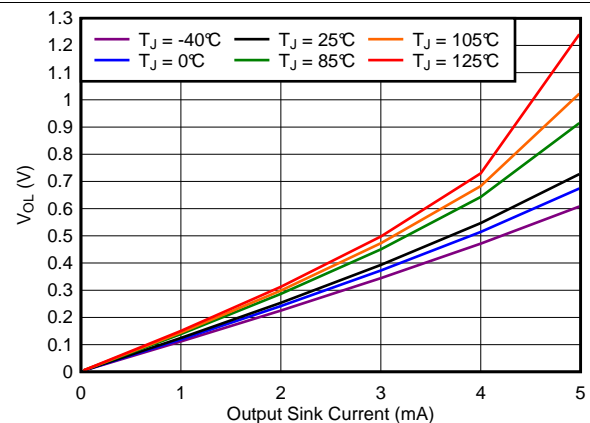


Figure 7. Output Voltage Low vs Output Current
(VDD = 1.5 V)

Typical Characteristics (continued)

at $T_J = 25^\circ\text{C}$ with a 0.1- μF capacitor close to VDD (unless otherwise noted)

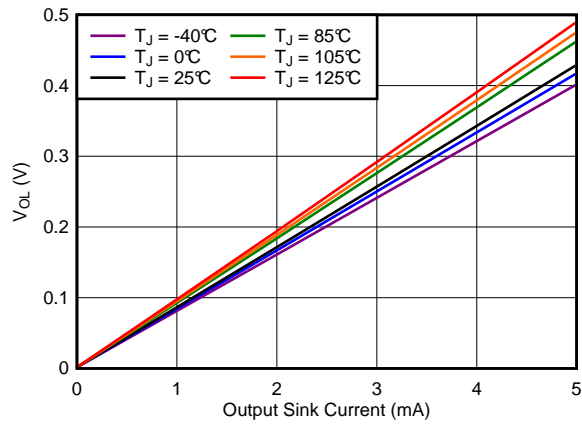


Figure 8. Output Voltage Low vs Output Current
(VDD = 3.3 V)

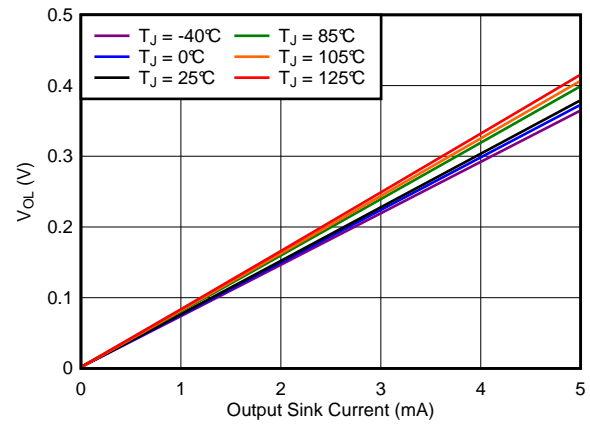


Figure 9. Output Voltage Low vs Output Current
(VDD = 5.5 V)

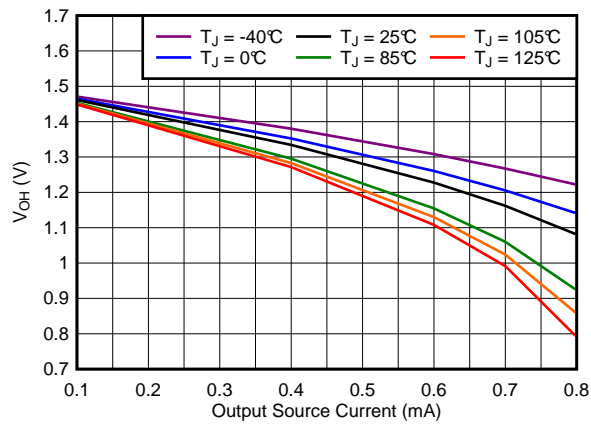


Figure 10. Output Voltage High vs Output Current
(VDD = 1.5 V)

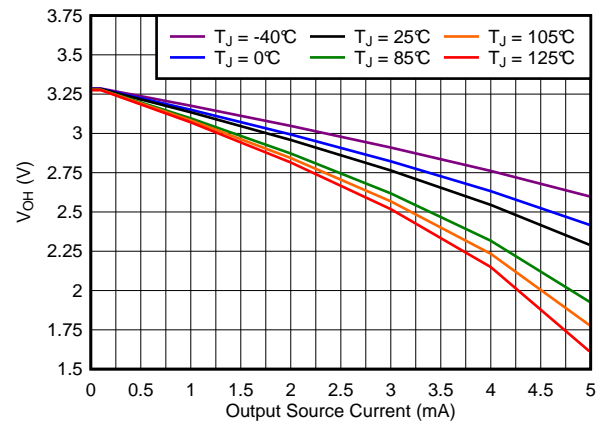


Figure 11. Output Voltage High vs Output Current
(VDD = 3.3 V)

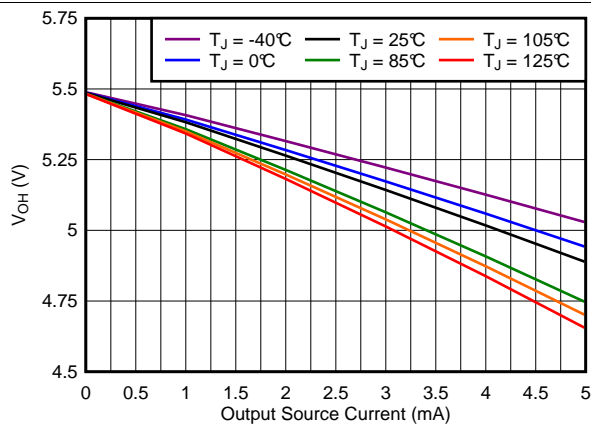


Figure 12. Output Voltage High vs Output Current
(VDD = 5.5 V)

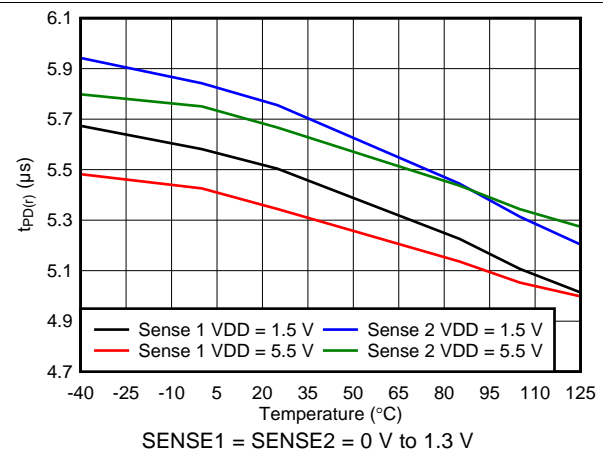


Figure 13. Propagation Delay from
SENSEx High to Output High

Typical Characteristics (continued)

at $T_J = 25^\circ\text{C}$ with a 0.1- μF capacitor close to VDD (unless otherwise noted)

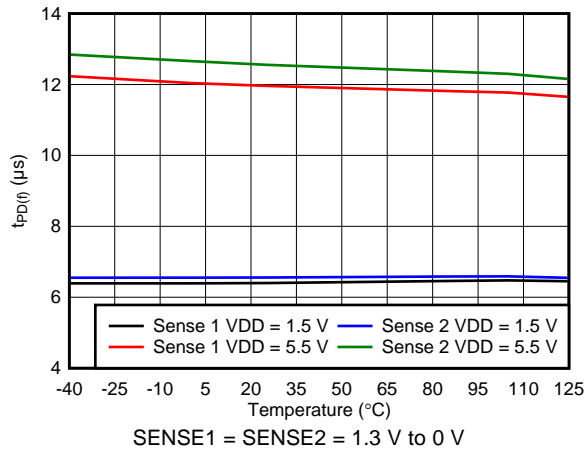


Figure 14. Propagation Delay from SENSEx Low to Output Low

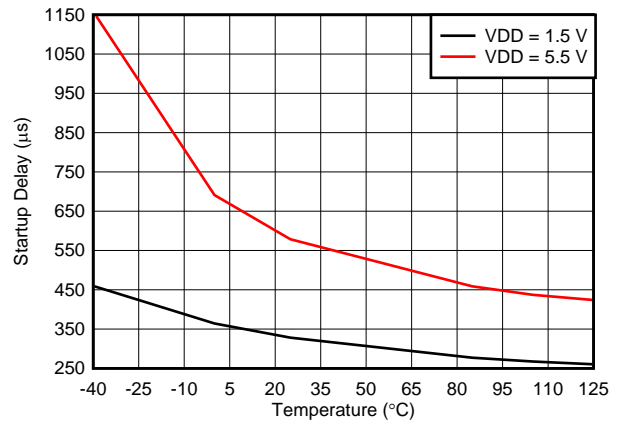


Figure 15. Startup Delay

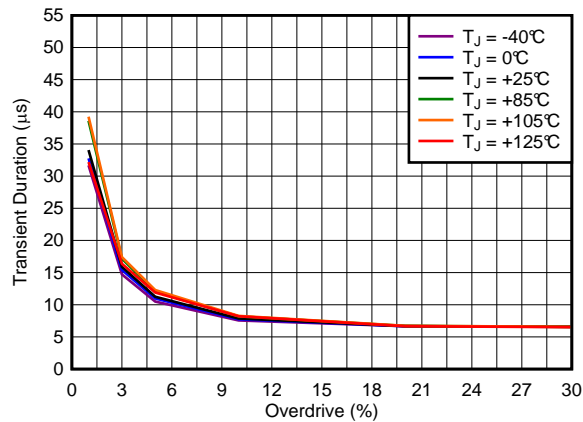


Figure 16. Minimum Transient Duration vs Overdrive (VDD = 1.5 V)

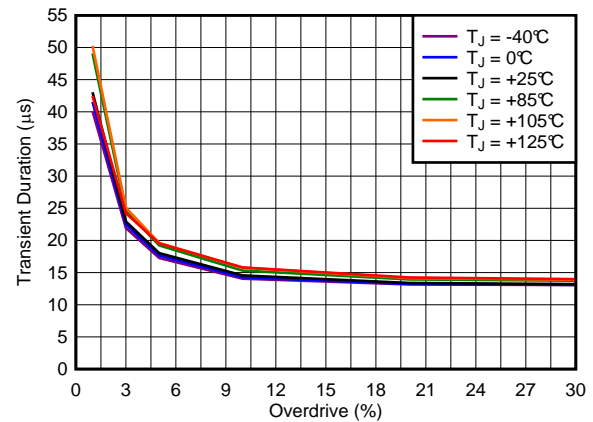


Figure 17. Minimum Transient Duration vs Overdrive (VDD = 5.5 V)

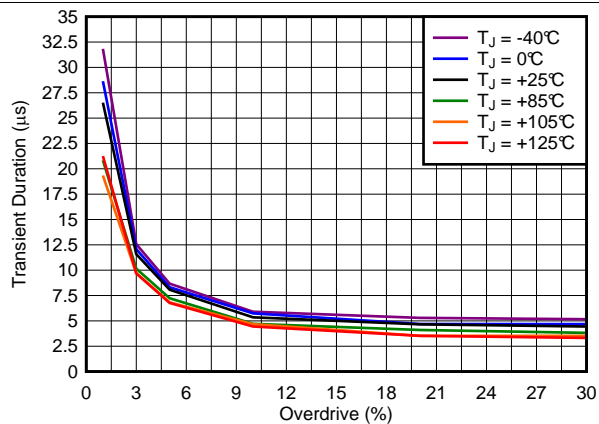


Figure 18. Minimum Transient Duration vs Overdrive (VDD = 1.5 V)

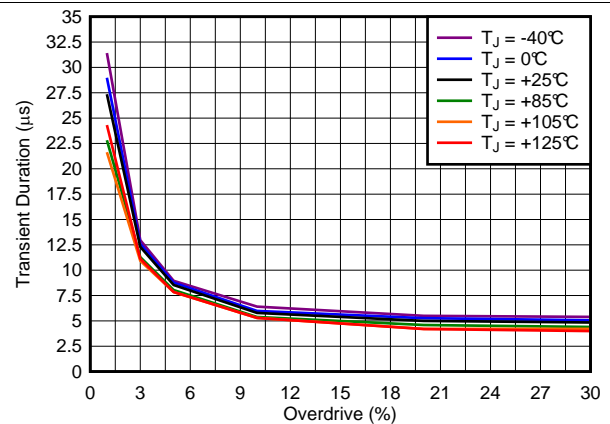


Figure 19. Minimum Transient Duration vs Overdrive (VDD = 5.5 V)

8 Detailed Description

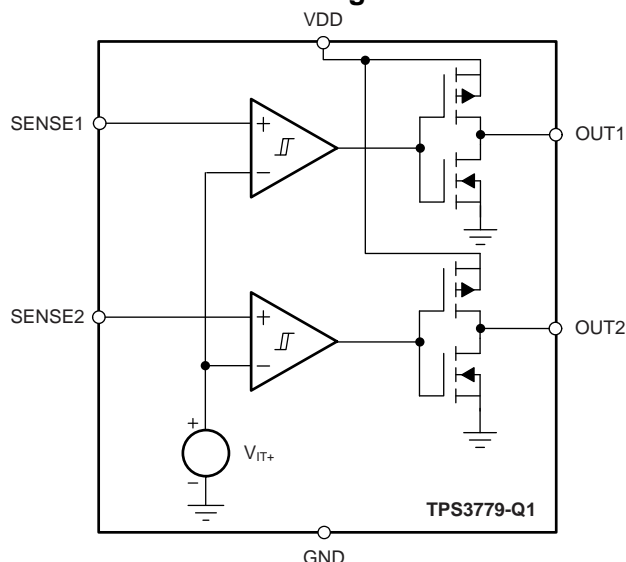
8.1 Overview

The TPS3779-Q1 and TPS3780-Q1 are small, low quiescent current (I_{DD}), dual-channel voltage detectors. These devices have high-accuracy rising and falling input thresholds, and assert the output as shown in Table 1. The output (OUTx pin) goes low when the SENSEx pin is less than V_{IT-} and goes high when the pin is greater than V_{IT+} . The TPS3779-Q1 and TPS3780-Q1 offer two hysteresis options (5% and 10%) for use in a wide variety of applications. These devices have two independent voltage-detection channels that can be used in systems where multiple voltage rails are required to be monitored, or where one channel can be used as an early warning signal and the other channel can be used as the system reset signal.

Table 1. TPS3779-Q1, TPS3780-Q1 Truth Table

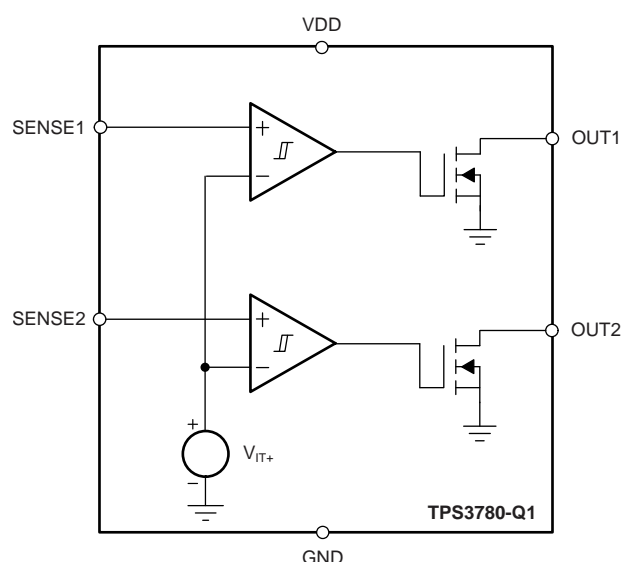
CONDITIONS	OUTPUT
$SENSE1 < V_{IT-}$	OUT1 = low
$SENSE2 < V_{IT-}$	OUT2 = low
$SENSE1 > V_{IT+}$	OUT1 = high
$SENSE2 > V_{IT+}$	OUT2 = high

8.2 Functional Block Diagrams



Copyright © 2016, Texas Instruments Incorporated

Figure 20. TPS3779-Q1 Block Diagram



Copyright © 2016, Texas Instruments Incorporated

Figure 21. TPS3780-Q1 Block Diagram

8.3 Feature Description

8.3.1 Inputs (SENSE1, SENSE2)

The TPS3779-Q1 and TPS3780-Q1 each have two comparators for voltage detection. Each comparator has one external input; the other input is connected to the internal reference. The comparator rising threshold is designed and trimmed to be equal to V_{IT+} , and the falling threshold is trimmed to be equal to V_{IT-} . The built-in falling hysteresis options make the devices immune to supply rail noise and ensure stable operation.

The comparator inputs can swing from ground to 5.5 V, regardless of the device supply voltage used. Although not required in most cases, for extremely noisy applications, good analog design practice is to place a 1-nF to 10-nF bypass capacitor at the comparator input in order to reduce sensitivity to transients and layout parasitic.

For each SENSEx input, the corresponding output (OUTx) is driven to logic low when the input voltage drops below V_{IT-} . When the voltage exceeds V_{IT+} , the output (OUTx) is driven high; see [Figure 1](#).

8.3.2 Outputs (OUT1, OUT2)

In a typical device application, the outputs are connected to a reset or enable input of another device, such as a digital signal processor (DSP), central processing unit (CPU), field-programmable gate array (FPGA), or application-specific integrated circuit (ASIC); or the outputs are connected to the enable input of a voltage regulator, such as a dc-dc or low-dropout (LDO) regulator.

The TPS3779-Q1 provides two push-pull outputs. The logic high level of the outputs is determined by the VDD pin voltage. Pullup resistors are not required with this configuration, thus saving board space. However, all interface logic levels must be examined. All OUTx connections must be compatible with the VDD pin logic level.

The TPS3780-Q1 provides two open-drain outputs (OUT1 and OUT2); pullup resistors must be used to hold these lines high when the output goes to a high-impedance condition (not asserted). By connecting pullup resistors to the proper voltage rails, the outputs can be connected to other devices at correct interface voltage levels. The outputs can be pulled up to 5.5 V, independent of the device supply voltage. To ensure proper voltage levels, make sure to choose the correct pullup resistor values. The pullup resistor value is determined by V_{OL} , the sink current capability, and the output leakage current ($I_{lkg(OD)}$). These values are specified in the [Electrical Characteristics](#) table. By using wired-AND logic, OUT1 and OUT2 can be combined into one logic signal. The [Inputs \(SENSE1, SENSE2\)](#) section describes how the outputs are asserted or deasserted. See [Figure 1](#) for a description of the relationship between threshold voltages and the respective output.

8.4 Device Functional Modes

8.4.1 Normal Operation ($VDD \geq VDD(min)$)

When the voltage on VDD is greater than VDD(min) for t_{SD} , the output signals react to the present state of the corresponding SENSEx pins.

8.4.2 Power-On-Reset ($VDD < V_{(POR)}$)

When the voltage on VDD is lower than the required voltage to internally pull the logic low output to GND ($V_{(POR)}$), both outputs are undefined and are not to be relied upon for proper system function.

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TPS3779-Q1 and TPS3780-Q1 are used as precision, dual-voltage detectors. The monitored voltage, VDD voltage, and output pullup voltage (TPS3780-Q1 only) can be independent voltages or connected in any configuration.

9.1.1 Threshold Overdrive

Threshold overdrive is how much V_{SENSE1} or V_{SENSE2} exceeds the specified threshold, and is important to know because a smaller overdrive results in a slower OUTx response. Threshold overdrive is calculated as a percent of the threshold in question, as shown in Equation 1:

$$\text{Overdrive} = | (V_{SENSE1,2} / V_{IT} - 1) \times 100\% |$$

where

- V_{IT} is either V_{IT-} or V_{IT+} , depending on whether calculating the overdrive for the negative-going threshold or the positive-going threshold, respectively
- $V_{SENSE1,2}$ is the voltage at the SENSE1 or SENSE2 input

(1)

Figure 16 illustrates the minimum detectable pulse on the SENSEx inputs versus overdrive, and is used to visualize the relationship that overdrive has on $t_{PD(f)}$ for negative-going events.

9.1.2 Sense Resistor Divider

The resistor divider values and target threshold voltage can be calculated by using Equation 2 and Equation 3 to determine $V_{MON(UV)}$ and $V_{MON(PG)}$, respectively.

$$V_{MON(UV)} = \left(1 + \frac{R1}{R2} \right) \times V_{IT-}$$

(2)

$$V_{MON(PG)} = \left(1 + \frac{R1}{R2} \right) \times V_{IT+}$$

(3)

where

- R1 and R2 are the resistor values for the resistor divider on the SENSEx pins
- $V_{MON(UV)}$ is the target voltage at which an undervoltage condition is detected
- $V_{MON(PG)}$ is the target voltage at which the output goes high when V_{MONx} rises

Choose R_{TOTAL} (equal to $R1 + R2$) so that the current through the divider is approximately 100 times higher than the input current at the SENSEx pins. The resistors can have high values to minimize current consumption as a result of low input bias current without adding significant error to the resistive divider. For details on sizing input resistors, see the [Optimizing Resistor Dividers at a Comparator Input](#) application report (SLVA450), available for download from www.ti.com.

9.2 Typical Applications

9.2.1 Monitoring Two Separate Rails

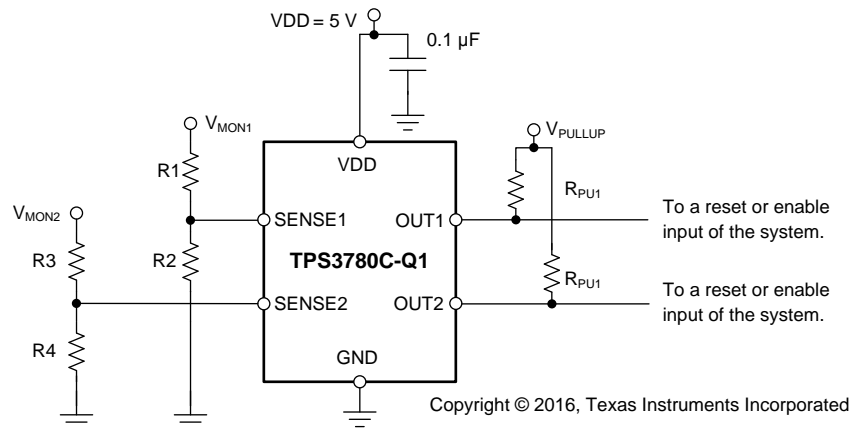


Figure 22. Monitoring Two Separate Rails Schematic

9.2.1.1 Design Requirements

Table 2. Design Parameters

PARAMETER	DESIGN REQUIREMENT	DESIGN RESULT
VDD	5 V	5 V
Hysteresis	10%	10%
Monitored voltage 1	3.3 V nominal, $V_{MON(PG)} = 2.9$ V, $V_{MON(UV)} = 2.6$ V	$V_{MON(PG)} = 2.908$ V, $V_{MON(UV)} = 2.618$ V
Monitored voltage 2	3 V nominal, $V_{MON(PG)} = 2.6$ V, $V_{MON(UV)} = 2.4$ V	$V_{MON(PG)} = 2.606$ V, $V_{MON(UV)} = 2.371$ V
Output logic voltage	3.3-V CMOS	3.3-V CMOS

9.2.1.2 Detailed Design Procedure

- Select the TPS3780C-Q1. The C version is selected to satisfy the hysteresis requirement. The TPS3780-Q1 is selected for the output logic requirement. An open-drain output allows for the output to be pulled up to a voltage other than VDD.
- The resistor divider values are calculated by using [Equation 2](#) and [Equation 3](#). For SENSE1, $R1 = 1.13$ M Ω and $R2 = 787$ k Ω . For SENSE2, $R3$ ($R1$) = 681 k Ω and $R4$ ($R2$) = 576 k Ω .

9.2.1.3 Application Curve

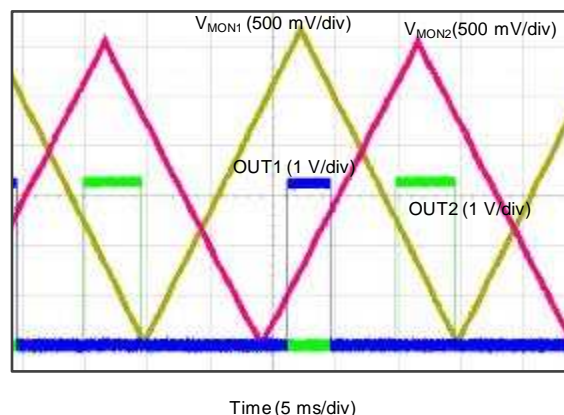
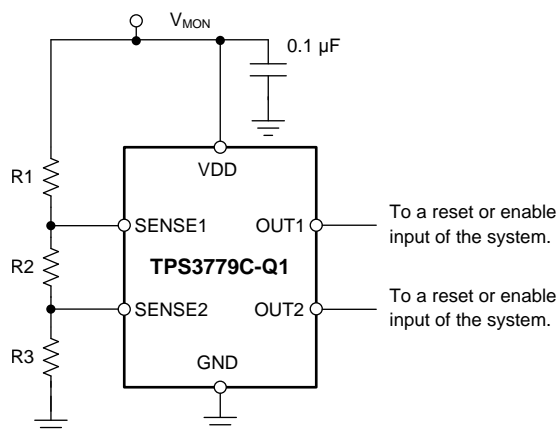


Figure 23. Monitoring Two Separate Rails Curve

9.2.2 Early Warning Detection



Copyright © 2016, Texas Instruments Incorporated

Figure 24. Early Warning Detection Schematic

9.2.2.1 Design Requirements

Table 3. Design Parameters

PARAMETER	DESIGN REQUIREMENT	DESIGN RESULT
VDD	V _{MON}	V _{MON}
Hysteresis	10%	10%
Monitored voltage 1	V _{MON(PG)} = 3.3 V, V _{MON(UV)} = 3 V	V _{MON(PG)} = 3.330 V, V _{MON(UV)} = 2.997 V
Monitored voltage 2	V _{MON(PG)} = 3.9 V, V _{MON(UV)} = 3.5 V	V _{MON(PG)} = 3.921 V, V _{MON(UV)} = 3.529 V

9.2.2.2 Detailed Design Procedure

1. Select the TPS3779C-Q1. The C version is selected to satisfy the hysteresis requirement. The TPS3779-Q1 is selected to save on component count and board space.
2. Use Equation 4 to calculate the total resistance for the resistor divider. Determine the minimum total resistance of the resistor network necessary to achieve the current consumption specification. For this example, the current flow through the resistor network is chosen to be 1.41 μA. Use the key transition point for V_{MON2}. For this example, the low-to-high transition, V_{MON(PG)}, is considered more important.

$$R_{TOTAL} = \frac{V_{MON(PG_2)}}{I} = \frac{3.9 \text{ V}}{1.41 \mu\text{A}} = 2.78 \text{ M}\Omega$$

where

- V_{MON(PG_2)} is the target voltage at which OUT2 goes high when V_{MON} rises
- I is the current flowing through the resistor network

3. After R_{TOTAL} is determined, R3 can be calculated using Equation 5. Select the nearest 1% resistor value for R3. In this case, 845 kΩ is the closest value.

$$R3 = \frac{V_{IT+}}{I} = \frac{1.194 \text{ V}}{1.41 \mu\text{A}} = 846 \text{ k}\Omega$$

4. Use Equation 6 to calculate R2. Select the nearest 1% resistor value for R2. In this case, 150 kΩ is the closest value. Use the key transition point for V_{MON1}. For this example, the high-to-low transition, V_{MON(UV)}, is considered more important.

$$R2 = \frac{R_{TOTAL}}{V_{MON(UV_1)}} \cdot V_{IT-} - R3 = \frac{2.78 \text{ M}\Omega}{3 \text{ V}} \cdot 1.074 \text{ V} - 845 \text{ k}\Omega = 149 \text{ k}\Omega$$

where

- V_{MON(UV_1)} is the target voltage at which OUT1 goes low when V_{MON} falls

5. Use Equation 7 to calculate R1. Select the nearest 1% resistor value for R1. In this case, 1.78 MΩ is a 1% resistor.

$$R1 = R_{TOTAL} - R2 - R3 = 2.78 \text{ M}\Omega - 150 \text{ k}\Omega - 845 \text{ k}\Omega = 1.78 \text{ M}\Omega \quad (7)$$

9.2.2.3 Application Curve

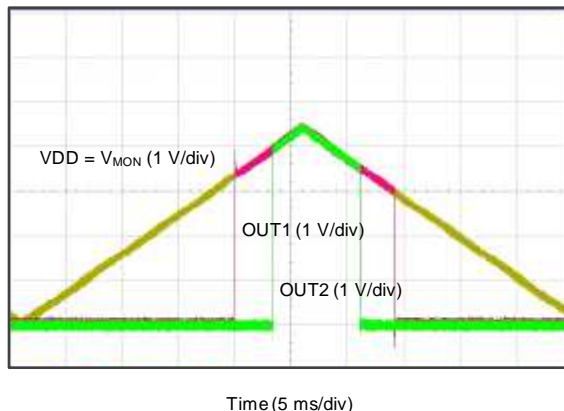


Figure 25. Early Warning Detection Curve

10 Power-Supply Recommendations

The TPS3779-Q1 and TPS3780-Q1 are designed to operate from an input voltage supply range between 1.5 V and 5.5 V. An input supply capacitor is not required for this device; however, good analog practice is to place a 0.1-μF or greater capacitor between the VDD pin and the GND pin. This device has a 7-V absolute maximum rating on the VDD pin. If the voltage supply providing power to VDD is susceptible to any large voltage transient that can exceed 7 V, additional precautions must be taken.

For applications where SENSEx is greater than 0 V before VDD, and is subject to a startup slew rate of less than 200 mV per 1 ms, the output can be driven to logic high in error. To correct the output, cycle the SENSEx lines below V_{IT-} or sequence SENSEx after VDD.

11 Layout

11.1 Layout Guidelines

Place the VDD decoupling capacitor close to the device.

Avoid using long traces for the VDD supply node. The VDD capacitor, along with parasitic inductance from the supply to the capacitor, can form an LC tank circuit that creates ringing with peak voltages above the maximum VDD voltage.

11.2 Layout Example

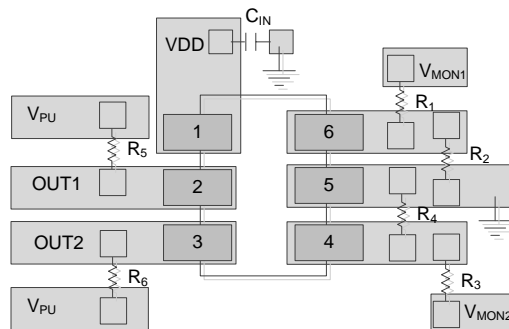


Figure 26. Example SOT-23 Layout

12 Device and Documentation Support

12.1 Device Support

12.1.1 Development Support

12.1.1.1 Evaluation Modules

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS3779-Q1 and TPS3780-Q1. The [TPS3780EVM-154 Evaluation Module](#) details the design kits and evaluation modules for the TPS3780EVM-154.

The EVM can be requested at [Texas Instruments](#) through the [TPS3779-Q1](#) and [TPS3780-Q1](#) product folders, or purchased [directly from the TI eStore](#).

12.1.1.2 Spice Models

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TPS3779-Q1 and TPS3780-Q1 is available through the respective device product folders under *Simulation Models*.

12.1.2 Device Nomenclature

The TPS3779xQyyyzQ1 and TPS3780xQyyyzQ1 are the generic naming conventions for these devices. The TPS3779-Q1 and TPS3780-Q1 represent the family of these devices; x is used to display the hysteresis version, yyy is reserved for the package designator, and z is the package quantity.

- Example: TPS3780CDBVRQ1
- Family: TPS3780-Q1 (open-drain)
- Hysteresis: 10%
- DBV package: 6-pin SOT-23
- Package quantity: R is for 3000 pieces

12.2 Documentation Support

12.2.1 Related Documentation

For related documentation see the following:

- [TPS3780EVM-154 Evaluation Module](#) (SLVU796)
- [Optimizing Resistor Dividers at a Comparator Input Application Report](#) (SLVA450)

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 4. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TPS3779-Q1	Click here	Click here	Click here	Click here	Click here
TPS3780-Q1	Click here	Click here	Click here	Click here	Click here

12.5 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.6 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

12.7 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.8 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS3779BQDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	12OE	Samples
TPS3779CQDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	12PE	Samples
TPS3780AQDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	12FE	Samples
TPS3780BQDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	12GE	Samples
TPS3780CQDBVRQ1	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	12HE	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS3779-Q1, TPS3780-Q1 :

- Catalog: [TPS3779](#), [TPS3780](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3779BQDBVRQ1	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3779CQDBVRQ1	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3780AQDBVRQ1	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3780BQDBVRQ1	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
TPS3780CQDBVRQ1	SOT-23	DBV	6	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS

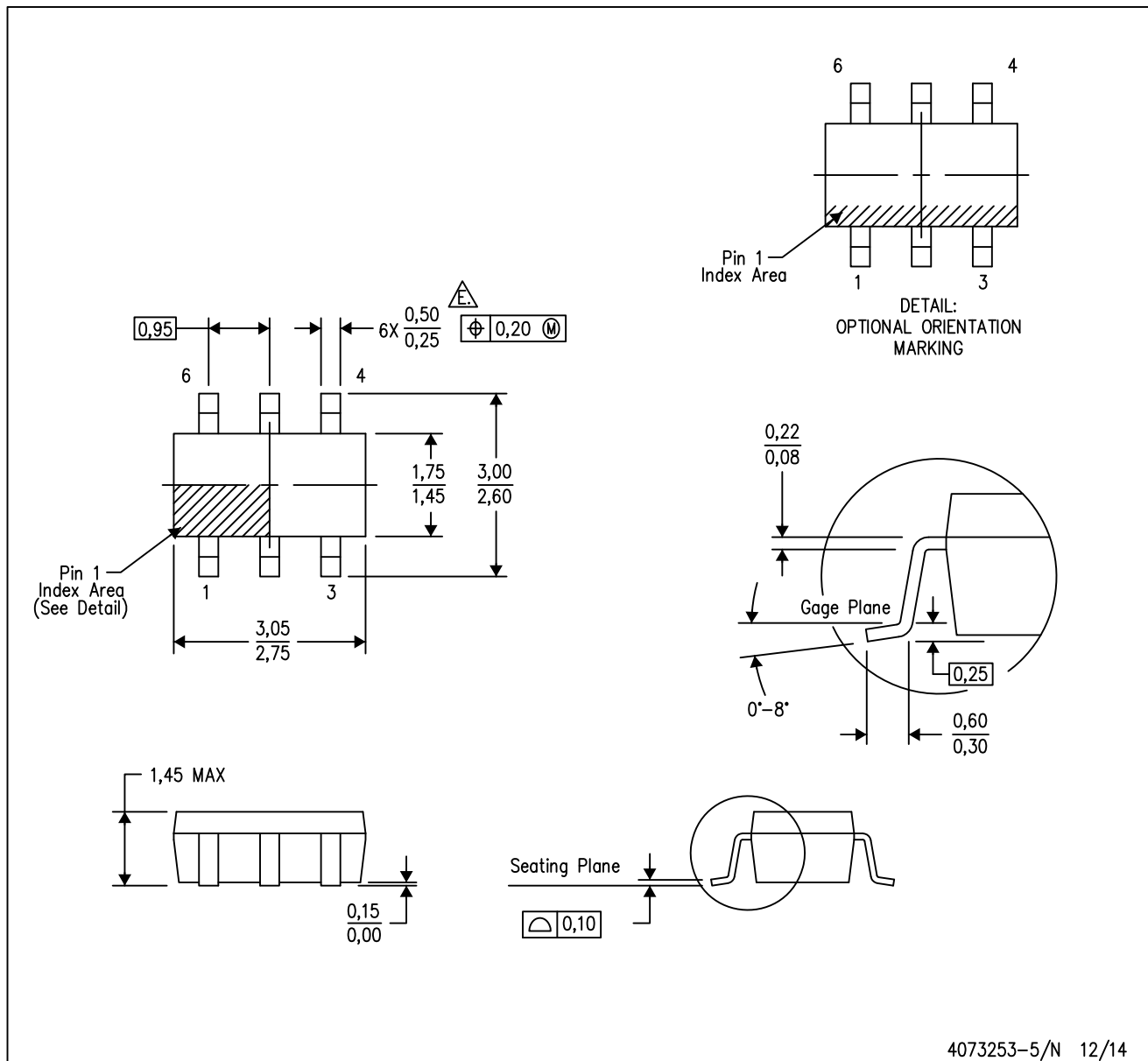


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3779BQDBVRQ1	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3779CQDBVRQ1	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3780AQDBVRQ1	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3780BQDBVRQ1	SOT-23	DBV	6	3000	180.0	180.0	18.0
TPS3780CQDBVRQ1	SOT-23	DBV	6	3000	180.0	180.0	18.0

DBV (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE

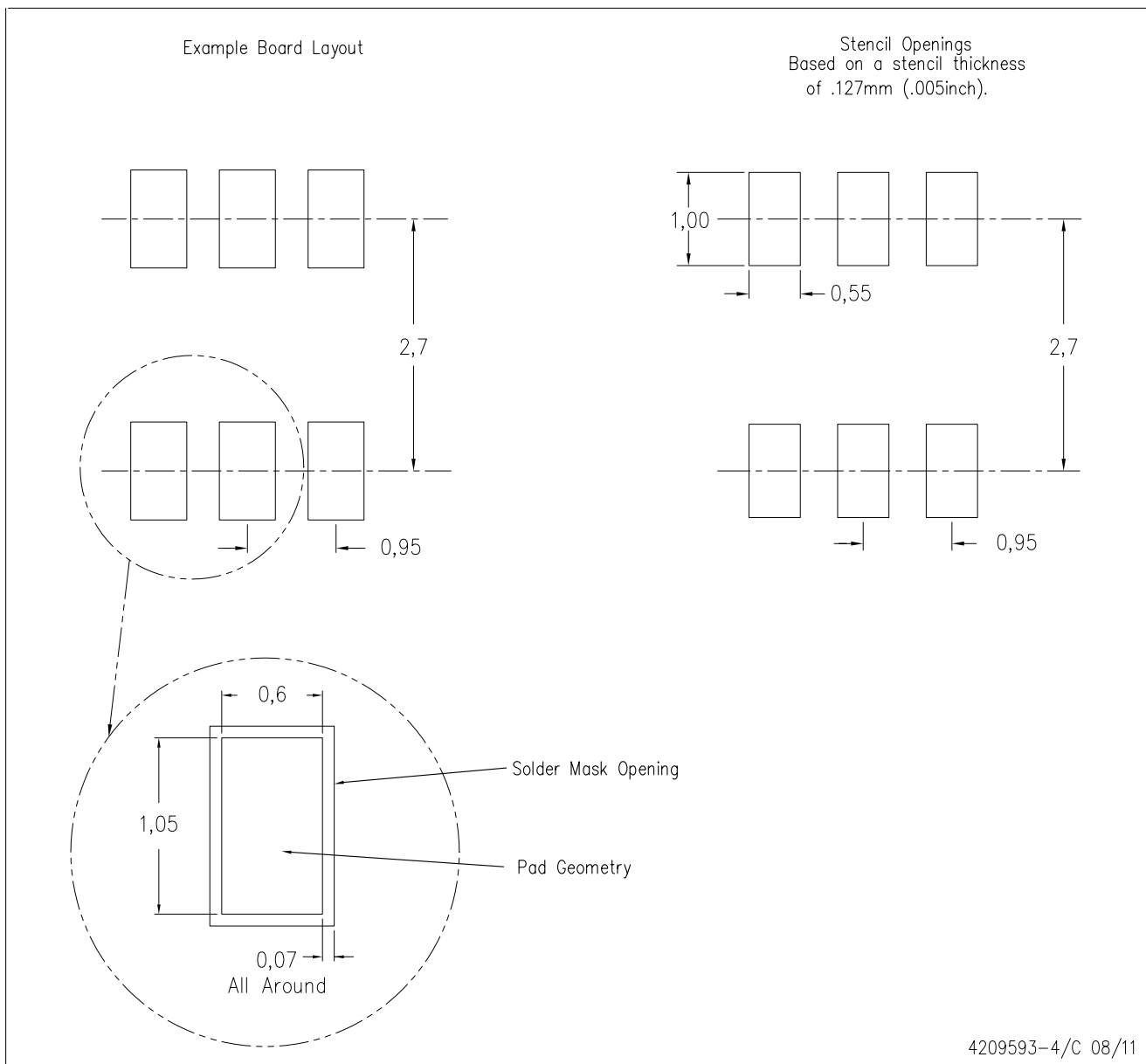


4073253-5/N 12/14

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
 - E. Falls within JEDEC MO-178 Variation AB, except minimum lead width.

DBV (R-PDSO-G6)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
 - D. Publication IPC-7351 is recommended for alternate designs.
 - E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com